

**UTC** UNISONIC TECHNOLOGIES CO., LTD

## 6N70-CB

Preliminary

# 6.0A, 700V N-CHANNEL POWER MOSFET

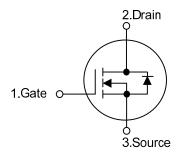
### DESCRIPTION

The UTC 6N70-CB is a high voltage MOSFET designed to have better characteristics, such as fast switching time, low gate charge, low on-state resistance and high rugged avalanche characteristics. This power MOSFET is usually used at high speed switching applications in power supplies, PWM motor controls, high efficient DC to DC converters and bridge circuits.

#### **FEATURES**

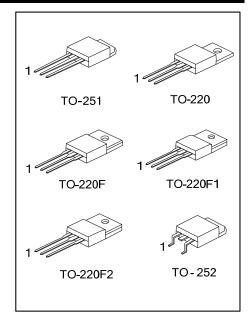
- \*  $R_{DS(ON)}$  < 2.04 $\Omega$  @  $V_{GS}$  = 10V ,  $I_D$  = 3.0A
- \* Fast switching capability
- \* Avalanche energy specified
- \* Improved dv/dt capability, high ruggedness

#### SYMBOL



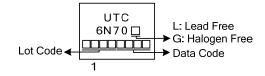
#### **ORDERING INFORMATION**

Ordering Number		Daakaga	Pin Assignment			Packing	
Lead Free	Halogen Free	Package	1	2	3	Facking	
6N70L-TA3-T	6N70G-TA3-T	TO-220	G	D	S	Tube	
6N70L-TF1-T	6N70G-TF1-T	TO-220F1	G	D	S	Tube	
6N70L-TF3-T	6N70G-TF3-T	TO-220F	G	D	S	Tube	
6N70L-TM3-T	6N70G-TM3-T	TO-251	G	D	S	Tube	
6N70L-TN3-R	6N70G-TN3-R	TO-252	G	D	S	Tape Reel	
Note: Pin Assignment: G: Gate D: Drain S: Source							
6N70L-TA3-T	<ul> <li>(1) T: Tube, R: Tape Reel</li> <li>(2) TA3: TO-220, TF1: TO-220F1, TF3: TO-220F</li> <li>TM3: TO-251, TN3: TO-252</li> <li>(3) L: Lead Free, G: Halogen Free and Lead Free</li> </ul>						
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#### MARKING





#### ■ ABSOLUTE MAXIMUM RATINGS (T<sub>c</sub> = 25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V <sub>DSS</sub>	700	V
Gate-Source Voltage		V <sub>GSS</sub>	±30	V
Drain Current	Continuous	I <sub>D</sub>	6.0	А
	Pulsed (Note 2)	I <sub>DM</sub>	24	А
Avalanche Current (Note 2)		I <sub>AR</sub>	2.6	А
Avalanche Energy	Single Pulsed (Note 3)	ed (Note 3) E <sub>AS</sub> 34		mJ
Peak Diode Recovery dv/dt (Note 4)		dv/dt	3.2	V/ns
Power Dissipation	TO-220		125	W
	TO-220F/TO-220F1 TO-220F2	P <sub>D</sub>	42	W
	TO-251/TO-252		55	W
Junction Temperature		TJ	+150	°C
Storage Temperature		T <sub>STG</sub>	-55 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied. 2. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Repetitive Rating. Pulse width inflited by maximum junction te 2. -10mH L -2.64 V -50V R -25.0 Storting T  $-25^{\circ}$ C

3. L=10mH, I<sub>AS</sub>=2.6A, V<sub>DD</sub>=50V, R<sub>G</sub>=25  $\Omega$ , Starting T<sub>J</sub> = 25°C 4. I<sub>SD</sub>≤6.0A, di/dt≤200A/µs, V<sub>DD</sub>≤ BV<sub>DSS</sub>, Starting T<sub>J</sub> = 25°C

#### THERMAL DATA

PARAMETER		SYMBOL	RATING	UNIT
Junction to Ambient	TO-220/TO-220F TO-220F1/TO-220F2	θ <sub>JA</sub>	62.5	°C/W
	TO-251/TO-252		110	°C/W
Junction to Case	TO-220		1.0	°C/W
	TO-220F/TO-220F1 TO-220F2	θ <sub>JC</sub>	2.98	°C/W
	TO-251/TO-252		2.27	°C/W



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#### ■ ELECTRICAL CHARACTERISTICS (T<sub>J</sub> = 25°C, unless otherwise specified)

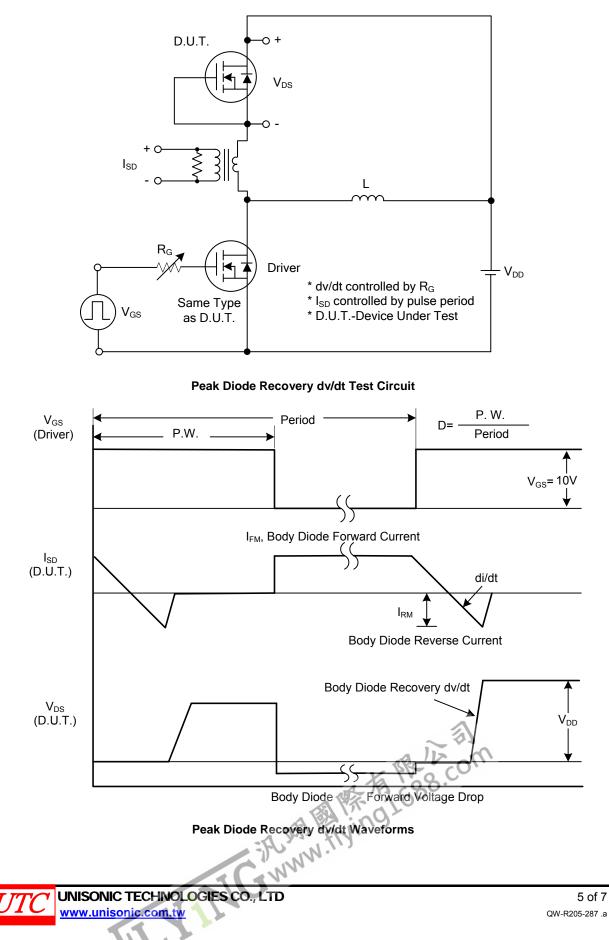
PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	ΜΑΧ	UNIT
OFF CHARACTERISTICS		OTMBOL				100 0 0	UNIT
Drain-Source Breakdown Voltage		BV <sub>DSS</sub>	V <sub>GS</sub> = 0V, I <sub>D</sub> = 250µA	700			V
Drain-Source Leakage Current		I <sub>DSS</sub>	$V_{DS} = 700V, V_{GS} = 0V$			1	μA
Gate-Source Leakage Current	Forward	- I <sub>GSS</sub>	$V_{GS} = 30V, V_{DS} = 0V$			100	nA
	Reverse		$V_{GS} = -30V, V_{DS} = 0V$			-100	nA
ON CHARACTERISTICS			• • •				
Gate Threshold Voltage		V <sub>GS(TH)</sub>	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	2.0		4.0	V
Static Drain-Source On-State Resistance		R <sub>DS(ON)</sub>	V <sub>GS</sub> = 10V, I <sub>D</sub> =3.0A			2.04	Ω
DYNAMIC CHARACTERISTICS						_	
Input Capacitance		CISS			1000		рF
Output Capacitance		Coss	V <sub>DS</sub> =25V, V <sub>GS</sub> =0V, f =1MHz		75		рF
Reverse Transfer Capacitance		C <sub>RSS</sub>			58		рF
SWITCHING CHARACTERISTIC	S						
Total Gate Charge (Note 1)		$Q_G$	V <sub>DS</sub> =50V, V <sub>GS</sub> =10V, I <sub>D</sub> =1.3A		66		nC
Gate to Source Charge		$Q_{GS}$	$V_{DS}=500$ , $V_{GS}=100$ , $I_{D}=1.3A$ $I_{G}=100\mu A$ (Note 1, 2)		5.5		nC
Gate to Drain Charge		$Q_{GD}$	IG-100μΑ (Note 1, 2)		5.2		nC
Turn-ON Delay Time (Note 1)		t <sub>D (ON)</sub>			55		ns
Rise Time		t <sub>R</sub>	V <sub>DS</sub> =30V, V <sub>GS</sub> =10V, I <sub>D</sub> =0.5A,		25		ns
Turn-OFF Delay Time		t <sub>D(OFF)</sub>	R <sub>G</sub> =25Ω (Note 1, 2)		173		ns
Fall-Time		t <sub>F</sub>			30		ns
SOURCE- DRAIN DIODE RATIN	GS AND CH	ARACTERIS	TICS				
Maximum Body-Diode Continuous Current		ls				6.0	Α
Maximum Body-Diode Pulsed Current		I <sub>SM</sub>				20	Α
Drain-Source Diode Forward Voltage (Note 1)		$V_{\text{SD}}$	I <sub>S</sub> =6.0A, V <sub>GS</sub> =0V			1.4	V
Body Diode Reverse Recovery Time (Note 1)		t <sub>rr</sub>	I <sub>S</sub> =6.0A, V <sub>GS</sub> =0V,		390		nS
Body Diode Reverse Recovery Charge		Qrr	dI <sub>F</sub> /dt=100A/µs		2.05		μC

Notes: 1. Pulse Test: Pulse width  $\leq$  300µs, Duty cycle $\leq$ 2%.

2. Essentially independent of operating temperature.



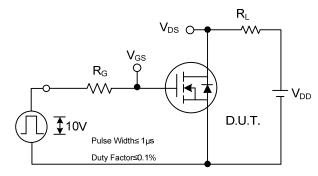
### TEST CIRCUITS AND WAVEFORMS

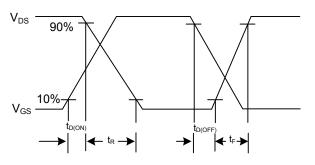


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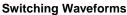
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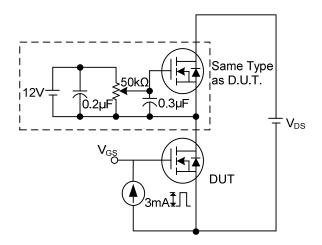
### TEST CIRCUITS AND WAVEFORMS (Cont.)





Switching Test Circuit

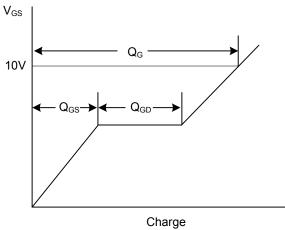


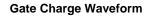


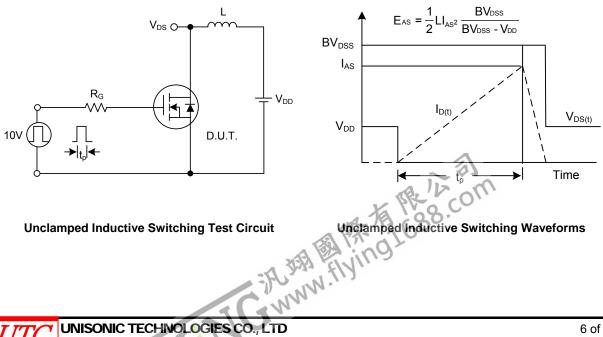


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